R16

Re	g.	No:												
	0	SIDDH	ARTI	H INS	TITU	TE O	F EN	GINE	ERIN	G&'	ГЕСЕ	INOL	OGY:: PUTTUF	2
(AUTONOMOUS)														-
	H	B.Tech I	I Year	· I Ser	nester	· Regu	lar ar	nd Su	pplem	entar	y Exa	minat	ions Nov/Dec 20	18
					BA	SICI	ELEC	CTR	ONI(C DE	VICI	ES		
							(ECE,	EEE)					
Tim	e: (3 hours											Max. Marks: 6	50
					(Ans	wer al	l Five	Units	<u>5 x 12</u>	2 = 60	Mark	s)		
								UNIT	`-I					
1	a	Derive a	an exp	ressio	n for (Contin	uity E	quatic	on.					6M
	b	Derive a	an exp	ressio	n for F	Fermi	level i	n an i	ntrinsi	c sem	icondu	ictor.		6M
								OR						
2	a	Explain the Diffusion and Drift currents for a semiconductor.												
	b	Explain	about	Energ	gy Ban	d Dia	grams	•						6M
UNIT-II														
3	a	Explain	the co	onstruc	ction a	nd wo	rking	of var	actor	diode	?			8M
	b	Define I	Holdin	ig curr	ent an	d Late	ching c	curren	t of S	CR				4M
4	•	Eveloin	tha r	vontrin	a of 7	Funnal	diad	OR	ita V	Laha	nostan	ation	And what is the	
4	a	Explain	the w	dition	g 01 1 for tu	nolin		e and	its v	-1 Cha	racter	istics.	And what is the	6M
	h	Explain	the co	nstruc	tion a	nd wo	g. rking	ofIC	ď					5M
	U	Explain		motra	uon u	ind wo	TRING T							5101
5	9	A bridge rectifier uses four identical diodes having forward resistance of 5 Ω each. Transformer secondary resistance is 5 Ω and the secondary voltage of 30V (rms).												
5	a													
		Determine the DC output voltage for IDC= 200mA and the value of the rip										lue of the ripple		
		voltage												
	b	b With neat diagram, explain Bridge Rectifier.												5M
								OR						
6	a	Discuss	the L	Sectio	on Filt	er witl	n neat	diagra	am					5M
	b	Design Two-section LC filter to provide an output voltage 9V with a load current of												
100 mA and the ripple is limited to 0.2% .												/M		
							L	JNIT-	-IV					
7	a	With ne	eat dia	ıgram,	expla	ain the	e Inpu	it and	Outp	ut cha	aracter	istics	of a BJT in CE	
	1	Configu	ration	•	<i>.</i> .	1	1.	C E	1		IOGE	гт		7M
	D	Explain	the co	onstruc	ction a	nd wo	rking	of En	hancei	ment I	MOSF	ET.		5M
								UK						
8	a	Explain	the w	orking	g of a I	PNP tr	ansist	or wit	h a ne	at diag	gram.			8M
	b	Compare CE, CB and CC configurations.												
							1	UNIT	-V					
9	a	Derive the condition for Thermal Stability to avoid thermal runaway.											6M	
	b	Explain the concept of DU and AU Load lines and discuss the criteria for fixing the												
		Q-point	•					OP						6M
10	In	a Self I	niae ci	reuit	contai	ning I	21=50	KO	R7=74	KO		ZO P	C=3KO $R=00$	
10	V	CC=12V	, VBF	=0.7V	7. Find	l the o	perati	12 DOI	nt. S.	S'.and	l S".	×32, N	~ J132, p=70,	12M

*** END ***